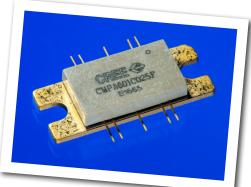


CMPA601C025F

25 W, 6.0 - 12.0 GHz, GaN MMIC, Power Amplifier

The CMPA601C025F is a gallium nitride (GaN) High Electron Mobility Transistor (HEMT) based monolithic microwave integrated circuit (MMIC) on a silicon carbide (SiC) substrate, using a 0.25 μ m gate length fabrication process. The semiconductor offers 25 Watts of power from 6 to 12 GHz of instantaneous bandwidth. The GaN HEMT MMIC is housed in a thermally-enhanced, 10-lead 25 mm x 9.9 mm metal/ceramic flanged package. It offers high gain and superior efficiency in a small footprint package at 50 ohms.



PN: CMPA601C025F Package Type: 440213

Typical Performance Over 6.0-12.0 GHz (T_c = 25°C)

| Parameter | 6.0 GHz | 7.5 GHz | 9.0 GHz | 10.5 GHz | 12.0 GHz | Units |
|---|---------|---------|---------|----------|----------|-------|
| Small Signal Gain | 35 | 34 | 34 | 37 | 31 | dB |
| P _{out} @ P _{IN} = 22 dBm | 34 | 51 | 49 | 49.5 | 36.5 | W |
| Power Gain @ P _⊪ = 22 dBm | 23 | 25 | 25 | 25 | 23.5 | dB |
| PAE @ P _{IN} = 22 dBm | 21 | 36 | 35 | 33 | 27 | % |

Note: All data CW.

Features

- 34 dB Small Signal Gain
- 40 W Typical P_{SAT}
- Operation up to 28 V
- High Breakdown Voltage
- High Temperature Operation
- Size 0.172 x 0.239 x 0.004 inches

Applications



- Jamming Amplifiers
- Test Equipment Amplifiers
- Broadband Amplifiers

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Absolute Maximum Ratings (not simultaneous) at 25°C

| Parameter | Symbol | Rating | Units | Conditions |
|---|-------------------|-----------|-----------------|----------------------------------|
| Drain-source Voltage | V _{DS} | 84 | V _{DC} | 25°C |
| Gate-source Voltage | V _{gs} | -10, +2 | V _{DC} | 25°C |
| Storage Temperature | T _{stg} | -40, +150 | °C | |
| Operating Junction Temperature | Tj | 225 | °C | |
| Maximum Forward Gate Current | I _{gmax} | 23 | mA | 25°C |
| Soldering Temperature ¹ | T _{stg} | 245 | °C | |
| Screw Torque | Т | 40 | in-oz | |
| Thermal Resistance, Junction to Case ² | R _{eJC} | 0.85 | °C/W | 85°C @ P _{DISS} = 116 W |
| Case Operating Temperature ² | T _c | -40, +150 | °C | |

Note¹ Refer to the Application Note on soldering at http://www.cree.com/rf/document-library

Note² See also, the Power Dissipation De-rating Curve on page 4

Electrical Characteristics (Frequency = 6.0 GHz to 12.0 GHz unless otherwise stated; $T_c = 25^{\circ}C$)

| Characteristics | Symbol | Min. | Тур. | Max. | Units | Conditions | |
|---------------------------------------|-------------------|------|------|------|-------|--|--|
| DC Characteristics ^{1,2} | | | | | | | |
| Gate Threshold | V _{TH} | -3.8 | -2.8 | -2.3 | V | V _{DS} = 10 V, I _D = 23 mA | |
| Saturated Drain Current | I _{DS} | 10.6 | 13.0 | - | А | $V_{_{DS}}$ = 6V, $V_{_{GS}}$ = 2 V | |
| Drain-Source Breakdown Voltage | V _{BD} | 84 | 100 | - | V | V _{GS} = -8 V, I _{DS} = 23 mA | |
| RF Characteristics ³ | | | | | | | |
| Small Signal Gain | S21 | 28 | 31 | - | dB | $V_{_{DD}}$ = 28 V, $I_{_{DQ}}$ = 2 A, $P_{_{\rm IN}}$ = -30 dBm | |
| Output Power ^{3,4} | P _{OUT1} | 45.5 | 47.2 | - | dBm | $V_{_{DD}}$ = 28 V, I $_{_{DQ}}$ = 2 A, $P_{_{IN}}$ = 22 dBm, Freq = 6 GHz | |
| Output Power ^{3,4} | P _{OUT2} | 45.5 | 47.1 | - | dBm | $V_{_{DD}}$ = 28 V, I $_{_{DQ}}$ = 2 A, P $_{_{\rm IN}}$ = 22 dBm, Freq = 9.5 GHz | |
| Output Power ^{3,4} | P _{OUT3} | 43.7 | 45.5 | - | dBm | $V_{_{DD}}$ = 28 V, $I_{_{DQ}}$ = 2 A, $P_{_{\rm IN}}$ = 22 dBm, Freq = 12 GHz | |
| Power Added Efficiency ^{3,4} | PAE ₁ | 23 | 33.2 | - | % | $V_{_{DD}}$ = 28 V, $I_{_{DQ}}$ = 2 A, $P_{_{IN}}$ = 22 dBm, Freq = 6 GHz | |
| Power Added Efficiency ^{3,4} | PAE ₂ | 26 | 32.3 | - | % | $V_{_{DD}}$ = 28 V, $I_{_{DQ}}$ = 2 A, $P_{_{\rm IN}}$ = 22 dBm, Freq = 9.5 GHz | |
| Power Added Efficiency ^{3,4} | PAE ₃ | 15.5 | 26.5 | - | % | $V_{_{DD}}$ = 28 V, $I_{_{DQ}}$ = 2 A, $P_{_{\rm IN}}$ = 22 dBm, Freq = 12 GHz | |
| Input Return Loss | S11 | - | -5 | - | dB | $V_{_{DD}}$ = 28 V, $I_{_{DQ}}$ = 2 A, $P_{_{IN}}$ = -30 dBm | |
| Output Return Loss | S22 | - | -5 | - | dB | $V_{_{DD}}$ = 28 V, $I_{_{DQ}}$ = 2 A, $P_{_{IN}}$ = -30 dBm | |
| Output Mismatch Stress | VSWR | - | 5:1 | VSWR | Ψ | No damage at all phase angles, V_{DD} = 28 V, I_{DQ} = 2 A, P_{IN} = 22 dBm | |

Notes:

¹ Measured on-wafer prior to packaging.

² Scaled from PCM data.

³ Measured in CMPA601C025F-AMP with 12.4 GHz low pass filter.

⁴ Fixture loss de-embedded using the following offsets. The offset is subtracted from the input offset value and added to the output offset value.

a) 6.0 GHz - 0.13 dB

b) 9.50 GHz - 0.26 dB

c) 12.0 GHz - 0.35 dB

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CMPA601C025F Typical Performance

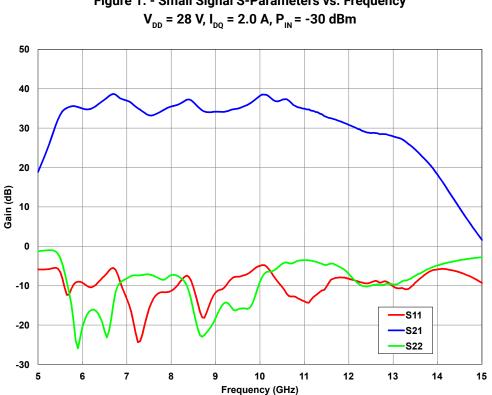
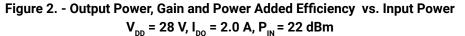
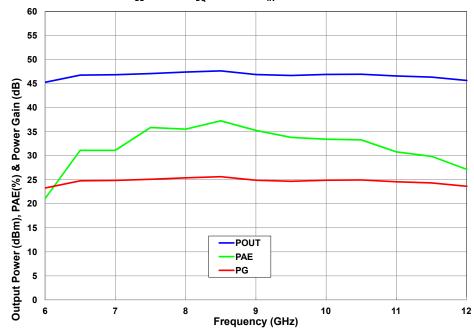


Figure 1. - Small Signal S-Parameters vs. Frequency



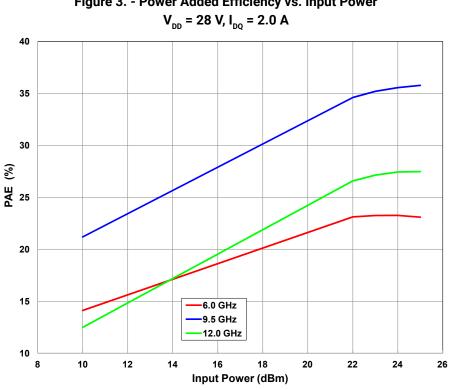


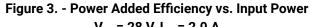
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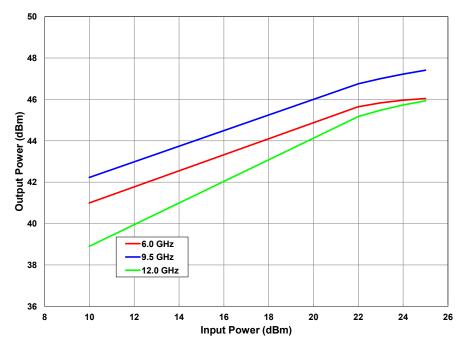


CMPA601C025F Typical Performance







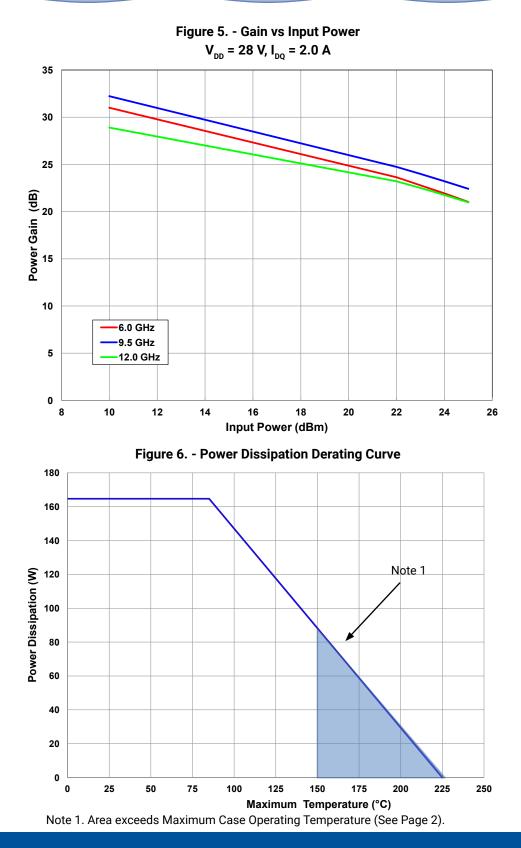


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CMPA601C025F Typical Performance



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CMPA601C025F-AMP Demonstration Amplifier Circuit Bill of Materials

| Designator | Description | Qty |
|---------------------|---|-----|
| C2,C4,C5,C7,C9,C12 | CAP,33000PF, 0805,100V, X7R | 6 |
| C1,C3,C6,C8,C10,C13 | CAP, 1.0UF, 100V, 10%, X7R, 1210 | 6 |
| C11,C14 | CAP ELECT 3.3UF 80V FK SMD | 2 |
| R1,R2 | RES 0.0 OHM 1/16W 0402 SMD | 2 |
| J1,J2 | CONN, SMA, PANEL MOUNT JACK, FLANGE, 4-HOLE, BLUNT POST, 20MIL | 2 |
| J3 | HEADER RT>PLZ .1CEN LK 9POS | 1 |
| W1 | WIRE, BLACK, 22 AWG ~ 1.50" | 1 |
| W2 | WIRE, BLACK, 22 AWG ~ 1.75" | 1 |
| Q1 | CMPA601C025F | 1 |

CMPA601C025F-AMP Demonstration Amplifier Circuit

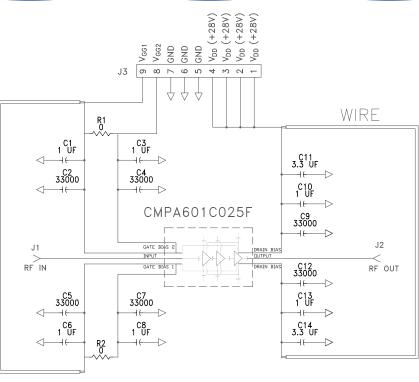


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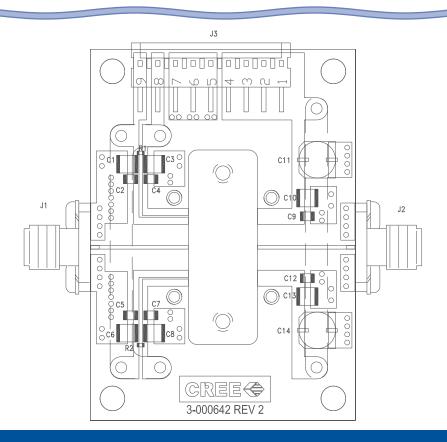
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CMP601C025F-AMP Demonstration Amplifier Circuit Schematic



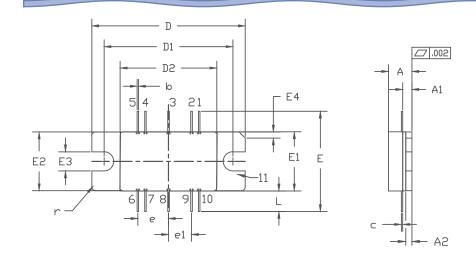
CMPA601C025F-AMP Demonstration Amplifier Circuit Outline



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Product Dimensions CMPA601C025F



| PIN | | 6: DRAIN BIAS |
|-----|--------------|----------------|
| | 2: GATE BIAS | 7: DRAIN BIAS |
| | 3: RF IN | 8 RF OUT |
| | 4: GATE BIAS | 9: DRAIN BIAS |
| | 5: GATE BIAS | 10: DRAIN BIAS |
| | | 11: SOURCE |

NDTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M - 1994.

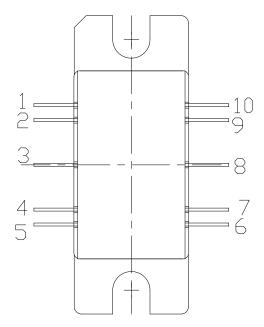
2. CONTROLLING DIMENSION: INCH.

3. ADHESIVE FR⊡M LID MAY EXTEND A MAXIMUM ⊡F 0.020″ BEY⊡ND EDGE ⊡F LID.

4. LID MAY BE MISALIGNED TO THE BODY OF PACKAGE BY A MAXIMUM OF 0.008" IN ANY DIRECTION.

| | INC | HES | MILLIMETERS | | NOTES |
|-----|-------|-------|-------------|-------|-------------|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 0.148 | 0.168 | 3.76 | 4.27 | |
| A1 | 0.055 | 0.065 | 1.40 | 1.65 | |
| A2 | 0.035 | 0.045 | 0.89 | 1.14 | |
| b | 0.01 | TYP | 0.254 | TYP | 10x |
| с | 0.007 | 0.009 | 0.18 | 0.23 | |
| D | 0.995 | 1.005 | 25.27 | 25.53 | |
| D1 | 0.835 | 0.845 | 21.21 | 21.46 | |
| D2 | 0.623 | 0.637 | 15.82 | 16.18 | |
| Е | 0.653 | TYP | 16.59 | TYP | |
| E1 | 0.380 | 0.390 | 9.65 | 9.91 | |
| E2 | 0.380 | 0.390 | 9.65 | 9.91 | |
| E3 | 0.120 | 0.130 | 3.05 | 3.30 | |
| E4 | 0.035 | 0.045 | 0.89 | 1.14 | 45° CHAMFER |
| е | 0.20 |) TYP | 5.08 TYP | | 4x |
| e1 | 0.15 |) TYP | 3.81 TYP | | 4x |
| L | 0.115 | 0.155 | 2.92 | 3.94 | 10x |
| r | 0.02 | 5 TYP | .635 TYP | | Зx |

| Pin Number | Qty |
|------------|------------------------------|
| 1 | Gate Bias for Stage 1, 2 & 3 |
| 2 | Gate Bias for Stage 1, 2 & 3 |
| 3 | RF IN |
| 4 | Gate Bias for Stage 1, 2 & 3 |
| 5 | Gate Bias for Stage 1, 2 & 3 |
| 6 | Drain Bias |
| 7 | Drain Bias |
| 8 | RF OUT |
| 9 | Drain Bias |
| 10 | Drain Bias |

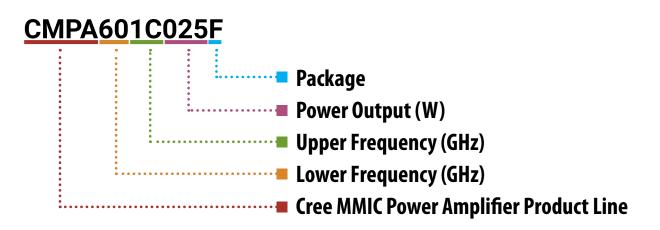


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Part Number System



| Parameter | Value | Units |
|------------------------------|---------|-------|
| Lower Frequency | 6.0 | GHz |
| Upper Frequency ¹ | 12.0 | GHz |
| Power Output | 25 | W |
| Package | Flanged | - |



Note¹: Alpha characters used in frequency code indicate a value greater than 9.9 GHz. See Table 2 for value.

| Character Code | Code Value |
|----------------|--------------------------------|
| А | 0 |
| В | 1 |
| С | 2 |
| D | 3 |
| E | 4 |
| F | 5 |
| G | 6 |
| н | 7 |
| J | 8 |
| К | 9 |
| Examples: | 1A = 10.0 GHz 2H = 27.0 GHz |

Table 2.

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Product Ordering Information

| Order Number | Description | Unit of Measure | Image |
|------------------|------------------------------------|-----------------|--------------|
| CMPA601C025F | GaN HEMT | Each | CHERTIC COST |
| CMPA601C025F-TB | Test board without GaN HEMT | Each | |
| CMPA601C025F-AMP | Test board with GaN HEMT installed | Each | |

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For more information, please contact:

Cree, Inc. 4600 Silicon Drive Durham, North Carolina, USA 27703 www.cree.com/RF

Sarah Miller Marketing Cree, RF Components 1.919.407.5302

Ryan Baker Marketing & Sales Cree, RF Components 1.919.407.7816

Tom Dekker Sales Director Cree, RF Components 1.919.407.5639

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